## Jacques Peretti

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/6016078/publications.pdf

Version: 2024-02-01

45 papers 1,936

331670 21 h-index 289244 40 g-index

46 all docs

46 docs citations

46 times ranked

2223 citing authors

#	Article	IF	CITATIONS
1	Direct Measurement of Auger Electrons Emitted from a Semiconductor Light-Emitting Diode under Electrical Injection: Identification of the Dominant Mechanism for Efficiency Droop. Physical Review Letters, 2013, 110, 177406.	7.8	564
2	Magneto-optical Effects Enhanced by Surface Plasmons in Metallic Multilayer Films. Physical Review Letters, 1994, 73, 3584-3587.	7.8	165
3	The efficiency challenge of nitride lightâ€emitting diodes for lighting. Physica Status Solidi (A) Applications and Materials Science, 2015, 212, 899-913.	1.8	112
4	Apertureless near-field optical microscopy: A study of the local tip field enhancement using photosensitive azobenzene-containing films. Journal of Applied Physics, 2003, 94, 2060-2072.	<b>2.</b> 5	101
5	Localization landscape theory of disorder in semiconductors. III. Application to carrier transport and recombination in light emitting diodes. Physical Review B, 2017, 95, .	3.2	95
6	Surface spectroscopy studies of Pb monolayers on Si(111). Surface Science, 1988, 204, 57-68.	1.9	78
7	Localization landscape theory of disorder in semiconductors. II. Urbach tails of disordered quantum well layers. Physical Review B, 2017, 95, .	3.2	78
8	Near-field optical patterning on azo-hybrid sol–gel films. Applied Physics Letters, 2001, 79, 4562-4564.	3.3	66
9	Monitoring the orientation of rare-earth-doped nanorods for flow shear tomography. Nature Nanotechnology, 2017, 12, 914-919.	31.5	65
10	Evidence of Two Distinct Mechanisms Driving Photoinduced Matter Motion in Thin Films Containing Azobenzene Derivatives. Journal of Physical Chemistry B, 2011, 115, 1363-1367.	2.6	58
11	Polarized Luminescence of Anisotropic LaPO <sub>4</sub> :Eu Nanocrystal Polymorphs. Journal of the American Chemical Society, 2018, 140, 9512-9517.	13.7	48
12	Optically Anisotropic Thin Films by Shearâ€Oriented Assembly of Colloidal Nanorods. Advanced Materials, 2013, 25, 3295-3300.	21.0	46
13	Spin-Dependent Transmission of Electrons through the Ferromagnetic Metal Base of a Hot-Electron Transistorlike System. Physical Review Letters, 1998, 80, 2425-2428.	7.8	45
14	Determination of the first satellite valley energy in the conduction band of wurtzite GaN by near-band-gap photoemission spectroscopy. Physical Review B, 2014, 89, .	3.2	38
15	Origin of electrons emitted into vacuum from InGaN light emitting diodes. Applied Physics Letters, 2014, 105, .	3.3	36
16	Surface Plasmon-Enhanced Fluorescence Spectroscopy on Silver Based SPR Substrates. Journal of Physical Chemistry C, 2010, 114, 22582-22589.	3.1	33
17	A closer look at the light-induced changes in the mechanical properties of azobenzene-containing polymers by statistical nanoindentation. Journal of Materials Chemistry C, 2015, 3, 11055-11065.	5 <b>.</b> 5	27
18	Evidence for trap-assisted Auger recombination in MBE grown InGaN quantum wells by electron emission spectroscopy. Applied Physics Letters, 2020, 116, .	3.3	23

#	Article	IF	Citations
19	Band structure of indium phosphide from near-band-gap photoemission. Physical Review B, 1991, 44, 7999-8008.	3.2	22
20	Remanent photoinduced birefringence in thin photochromic sol–gel films. Applied Physics Letters, 1999, 74, 1657-1659.	3.3	22
21	High-resolution energy analysis of field-assisted photoemission: A spectroscopic image of hot-electron transport in semiconductors. Physical Review B, 1993, 47, 3603-3619.	3.2	21
22	Imaging of magnetic domains with scanning tunneling optical microscopy. Journal of Applied Physics, 1998, 83, 6834-6836.	2.5	21
23	Near-field magneto-optics with polarization sensitive STOM. Ultramicroscopy, 1995, 57, 270-276.	1.9	19
24	Direct measurement of hot-carrier generation in a semiconductor barrier heterostructure: Identification of the dominant mechanism for thermal droop. Physical Review B, 2019, 100, .	3.2	16
25	Novel photoemission approach to hot-electron transport in semiconductors. Physical Review Letters, 1990, 64, 1682-1685.	7.8	15
26	Ultrafast electron dynamics reveal the high potential of InSe for hot-carrier optoelectronics. Physical Review B, 2018, 97, .	3.2	15
27	Optimized combination of intrinsic and form birefringence in oriented LaPO4 nanorod assemblies. Applied Physics Letters, 2014, 105, 061102.	3.3	14
28	Transport and magnetic properties of Fe/GaAs Schottky junctions for spin polarimetry applications. Journal of Applied Physics, 2011, 109, 113708.	2.5	13
29	Near-field magneto-optical microscopy. Microscopy Microanalysis Microstructures, 1994, 5, 381-388.	0.4	11
30	Identification of low-energy peaks in electron emission spectroscopy of InGaN/GaN light-emitting diodes. Journal of Applied Physics, 2018, 124, .	2.5	10
31	Ultrafast dynamics of hot carriers in a quasi–two-dimensional electron gas on InSe. Proceedings of the National Academy of Sciences of the United States of America, 2020, 117, 21962-21967.	7.1	10
32	Quantitative correlation of hot electron emission to Auger recombination in the active region of $\langle i \rangle c \langle j \rangle$ , plane blue III-N LEDs. Applied Physics Letters, 2021, 119, .	3.3	10
33	Analytical descriptions of the band structure of direct-band-gap zinc-blende-structure semiconductors in theka‹pKane model. Physical Review B, 1991, 44, 7993-7998.	3.2	8
34	The formation of the Pb/Si(111) interface studied byin situellipsometry and surface spectroscopy. Physica Scripta, 1988, 38, 169-171.	2.5	6
35	<title>Design of optical components and optical data storage in photochromic sol-gel films containing dithienylethene or azobenzene derivatives</title> ., 2000, 3943, 32.		6
36	Identii $\neg c$ ation of Auger effect as the dominant mechanism for efficiency droop of LEDs. Proceedings of SPIE, 2014, , .	0.8	5

#	Article	IF	CITATIONS
37	Low-energy electro- and photo-emission spectroscopy of GaN materials and devices. Journal of Applied Physics, 2015, 117, 112814.	2.5	4
38	Auger effect identified as main cause of efficiency droop in LEDs. SPIE Newsroom, 0, , .	0.1	3
39	Optical Patterning of Sol–Gel Silica Coatings. Advanced Optical Materials, 2016, 4, 313-320.	7.3	2
40	Photoemission of metal-semiconductor structures: Novel spectroscopy for high field transport. Solid-State Electronics, 1989, 32, 1681-1684.	1.4	1
41	Spin-dependent electron transport in ferromagnetic bilayers: Application to three-dimensional spin detectors. Journal of Applied Physics, 2002, 91, 8408.	2.5	1
42	Lightâ€ŧunable optical cell manipulation via photoactive azobenzene ontaining thin film bioâ€substrate. Nano Select, 0, , .	3.7	1
43	Electron spin polarimeters based on the exchange asymmetry in ferromagnetic layers. , 2002, , .		O
44	Light tunable azopolymers: Photomechanical phenomena and multifunctional materials., 2019,,.		0
45	In-vivo, in-situ, light-tunable manipulation of cells' biomechanics on a photoactive azobenzene bio-substrate., 2022,,.		O